# 2SC3941

## Silicon NPN triple diffusion planar type

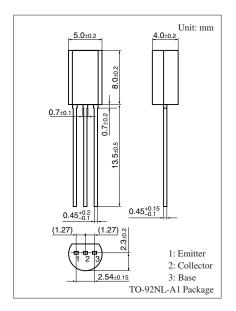
For high breakdown voltage general amplification For small TV video output Complementary to 2SA1858

#### ■ Features

- $\bullet$  High collector-emitter voltage (Base open)  $V_{\text{CEO}}$
- High transition frequency f<sub>T</sub>
- Allowing supply with the radial taping

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	300	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	300	V
Emitter-base voltage (Collector open)	$V_{EBO}$	7	V
Collector current	$I_C$	70	mA
Peak collector current	$I_{CP}$	100	mA
Collector power dissipation	P <sub>C</sub>	1	W
Junction temperature	$T_{j}$	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C



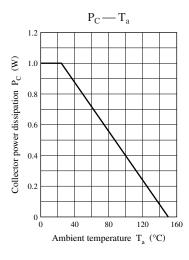
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

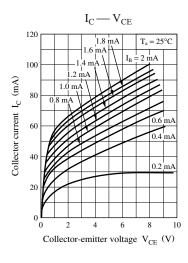
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_C = 100 \mu\text{A},  I_B = 0$	300			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 1 \mu A, I_C = 0$	7			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 100 \text{ V}, I_E = 0$			2	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	30		220	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$			1.2	V
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$	50	80		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		4	8	pF
(Common base, input open circuited)						
Storage time	t <sub>stg</sub>	$I_C = 100 \text{ mA}, I_{B1} = 10 \text{ mA}, I_{B2} = 0$		2.5		μs

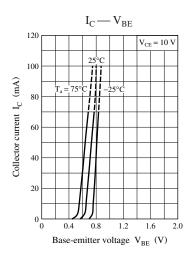
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

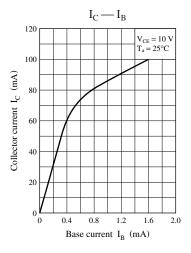
#### 2. \*: Rank classification

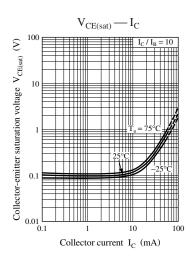
Rank	Р	Q	R
$h_{FE}$	30 to 100	60 to 150	100 to 220

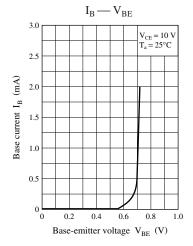


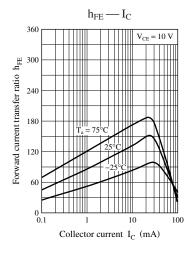


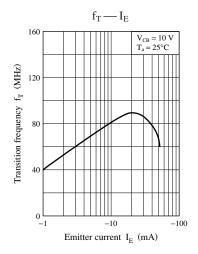


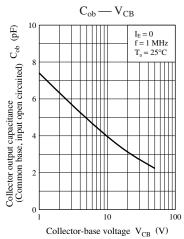




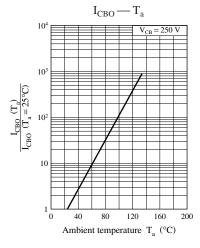


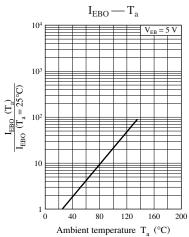


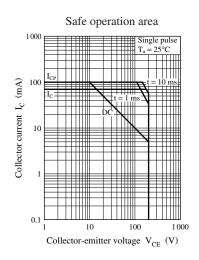




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